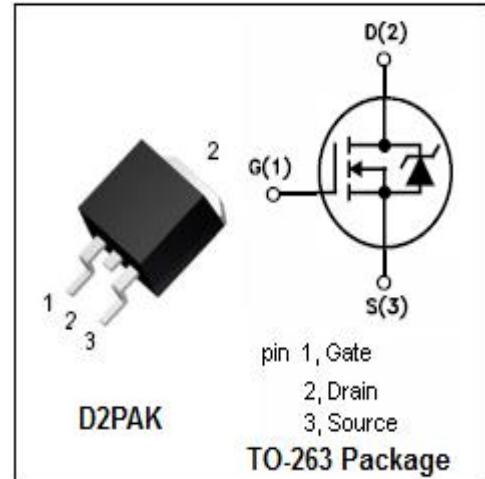


Isc N-Channel MOSFET Transistor

IRFS23N20D

• FEATURES

- With TO-263(D² PAK) packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



• APPLICATIONS

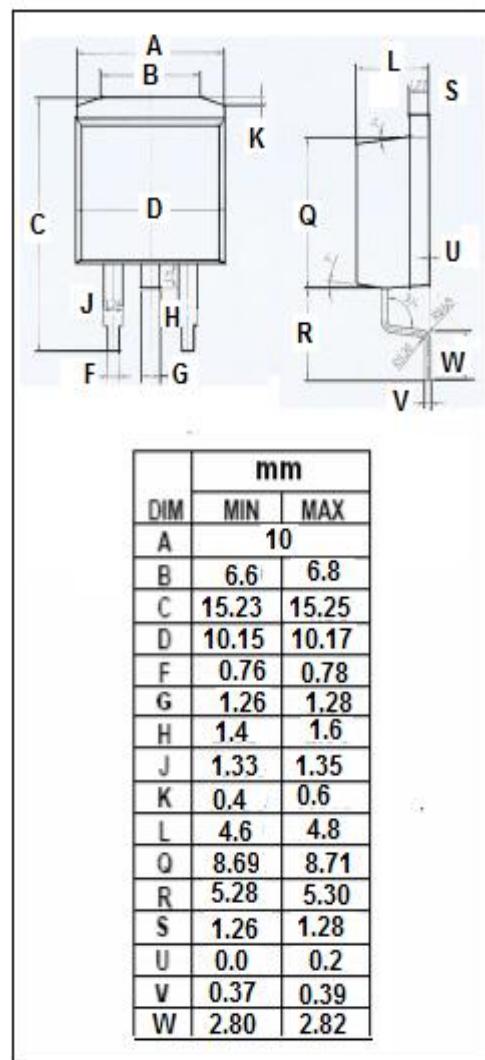
- Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	200	V
V _{GS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous	24	A
P _D	Total Dissipation @T _c =25°C	3.8	W
T _j	Max. Operating Junction Temperature	-55~175	°C
T _{stg}	Storage Temperature	-55~175	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(j-c)}	Channel-to-case thermal resistance	0.9	°C/W



Isc N-Channel MOSFET Transistor**IRFS23N20D****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}; I_{\text{D}}= 1\text{mA}$	200			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}; I_{\text{D}}= 250 \mu\text{A}$	3		5.5	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	$V_{\text{GS}}= 10\text{V}; I_{\text{D}}= 14\text{A}$			100	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{\text{GS}}= \pm 30\text{V}; V_{\text{DS}}= 0\text{V}$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{\text{DS}}= 200\text{V}; V_{\text{GS}}= 0\text{V}$			25	μA
V_{SD}	Diode forward voltage	$I_{\text{S}}= 14\text{A}, V_{\text{GS}}= 0\text{V}$			1.3	V

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